Data Sheet No. PD60161-R

International
IOR Rectifier

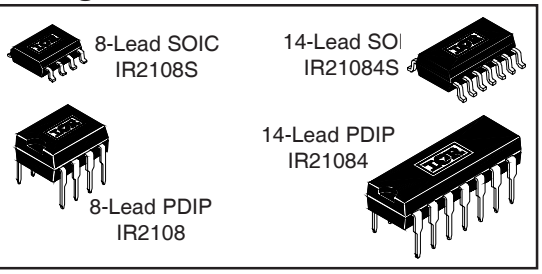
IR2108(4) (S) & (PbF)

HALF-BRIDGE DRIVER

Features

- Floating channel designed for bootstrap operation
  Fully operational to +600V
  Tolerant to negative transient voltage
  dV/dt immune
- Gate drive supply range from 10 to 20V
- Undervoltage lockout for both channels
- 3.3V, 5V and 15V input logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- High side output in phase with HIN input
- Low side output out of phase with LIN input
- Logic and power ground +/- 5V offset.
- Internal 540ns dead-time, and programmable up to 5us with one external R_{DT} resistor (IR21084)
- Lower di/dt gate driver for better noise immunity
- Available in Lead-Free

Packages



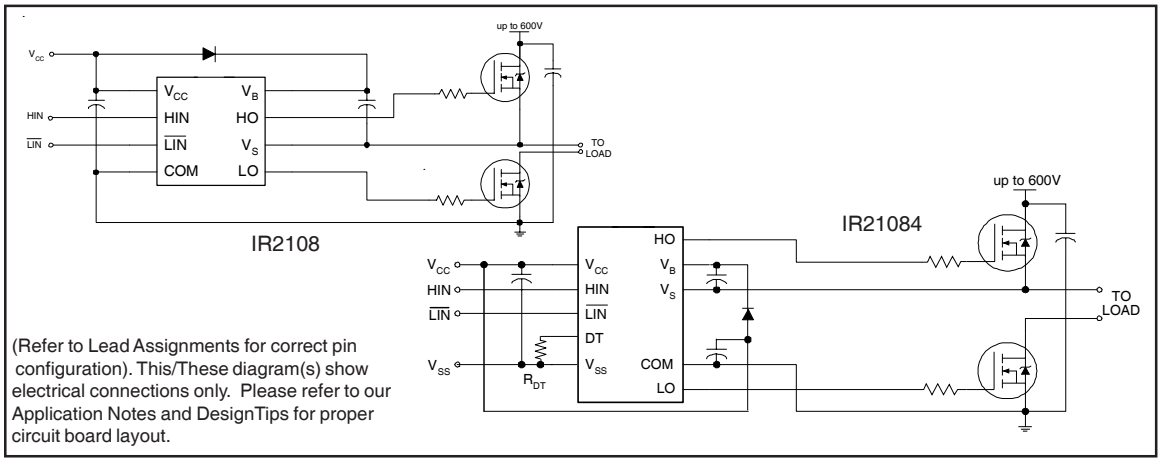
2106/2301//2108//2109/2302/2304 Feature Comparison

Part	Input logic	Cross-conduction prevention logic	Dead-Time	Ground Pins
2106/2301	HIN/LIN	no	none	COM
21064				VSS/COM
2108	HIN/$\overline{\text{LIN}}$	yes	Internal 540ns	COM
21084			Programmable 0.54~5 μs	VSS/COM
2109/2302	IN/$\overline{\text{SD}}$	yes	Internal 540ns	COM
21094			Programmable 0.54~5 μs	VSS/COM
2304	HIN/LIN	yes	Internal 100ns	COM

Description

The IR2108(4)(S) are high voltage, high speed power MOSFET and IGBT drivers with dependent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 volts.

Typical Connection



(Refer to Lead Assignments for correct pin configuration). This/These diagram(s) show electrical connections only. Please refer to our Application Notes and DesignTips for proper circuit board layout.

Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition		Min.	Max.	Units
V_B	High side floating absolute voltage		-0.3	625	V
V_S	High side floating supply offset voltage		V_B - 25	V_B + 0.3	
V_{HO}	High side floating output voltage		V_S - 0.3	V_B + 0.3	
V_{CC}	Low side and logic fixed supply voltage		-0.3	25	
V_{LO}	Low side output voltage		-0.3	V_{CC} + 0.3	
DT	Programmable dead-time pin voltage (IR21084 only)		V_{SS} - 0.3	V_{CC} + 0.3	
V_{IN}	Logic input voltage (HIN & $\overline{LIN}$)		V_{SS} - 0.3	V_{CC} + 0.3	
V_{SS}	Logic ground (IR21084 only)		V_{CC} - 25	V_{CC} + 0.3	
dV_S/dt	Allowable offset supply voltage transient		—	50	V/ns
P_D	Package power dissipation @ $T_A \leq +25°C$	(8 lead PDIP)	—	1.0	W
		(8 lead SOIC)	—	0.625	
		(14 lead PDIP)	—	1.6	
		(14 lead SOIC)	—	1.0	
Rth_{JA}	Thermal resistance, junction to ambient	(8 lead PDIP)	—	125	°C/W
		(8 lead SOIC)	—	200	
		(14 lead PDIP)	—	75	
		(14 lead SOIC)	—	120	
T_J	Junction temperature		—	150	°C
T_S	Storage temperature		-50	150	
T_L	Lead temperature (soldering, 10 seconds)		—	300	

Recommended Operating Conditions

The Input/Output logic timing diagram is shown in figure 1. For proper operation the device should be used within the recommended conditions. The V_S and V_{SS} offset rating are tested with all supplies biased at 15V differential.

Symbol	Definition		Min.	Max.	Units
VB	High side floating supply absolute voltage		V_S + 10	V_S + 20	V
V_S	High side floating supply offset voltage		Note 1	600	
V_{HO}	High side floating output voltage		V_S	V_B	
V_{CC}	Low side and logic fixed supply voltage		10	20	
V_{LO}	Low side output voltage		0	V_{CC}	
V_{IN}	Logic input voltage	IR2108	COM	V_{CC}	
		IR21084	V_{SS}	V_{CC}	
DT	Programmable dead-time pin voltage (IR21084 only)		V_{SS}	V_{CC}	
V_{SS}	Logic ground (IR21084 only)		-5	5	°C
T_A	Ambient temperature		-40	125	

Note 1: Logic operational for V_S of -5 to +600V. Logic state held for V_S of -5V to $-V_{BS}$. (Please refer to the Design Tip DT97-3 for more details).

Dynamic Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, V_{SS} = COM, C_L = 1000 pF, T_A = 25°C, DT = VSS unless otherwise specified.

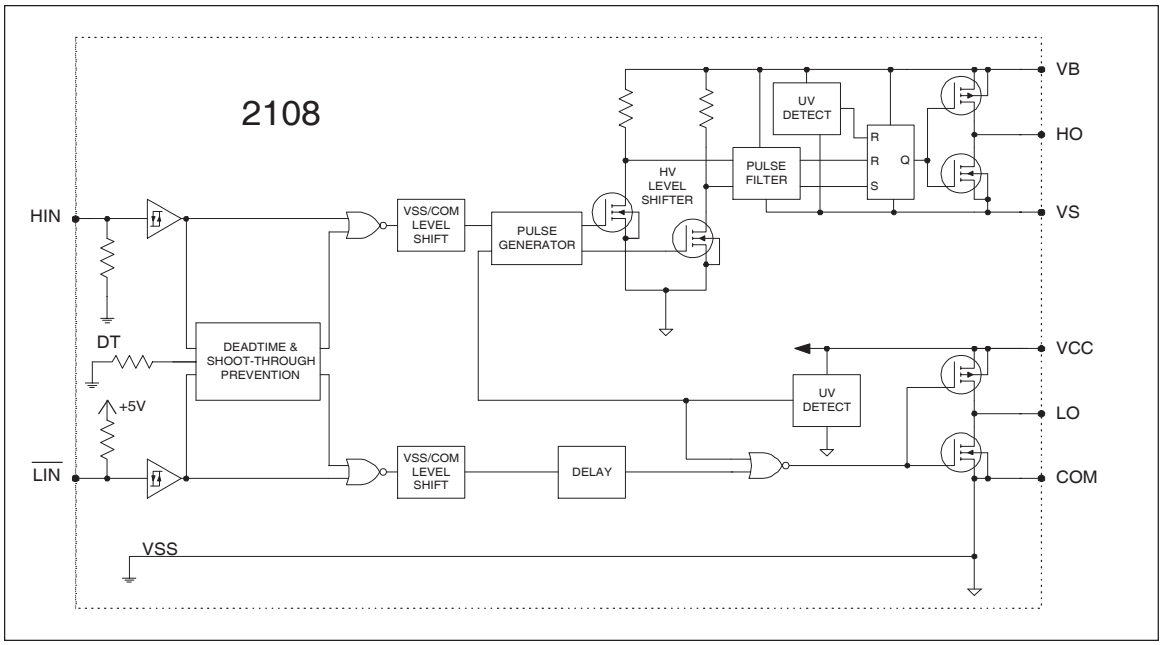
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
t_{on}	Turn-on propagation delay	—	220	300	nsec	V_S = 0V
t_{off}	Turn-off propagation delay	—	200	280		V_S = 0V or 600V
MT	Delay matching $\lvert t_{on} - t_{off} \rvert$	—	0	30		
t_r	Turn-on rise time	—	150	220		V_S = 0V
t_f	Turn-off fall time	—	50	80		V_S = 0V
DT	Deadtime: LO turn-off to HO turn-on(DT_{LO-HO}) &	400	540	680		RDT= 0
	HO turn-off to LO turn-on (DT_{HO-LO})	4	5	6	usec	RDT = 200k (IR21084)
MDT	Deadtime matching = $\lvert DT_{LO-HO} - DT_{HO-LO} \rvert$	—	0	60	nsec	RDT=0
		—	0	600		RDT = 200k (IR21084)

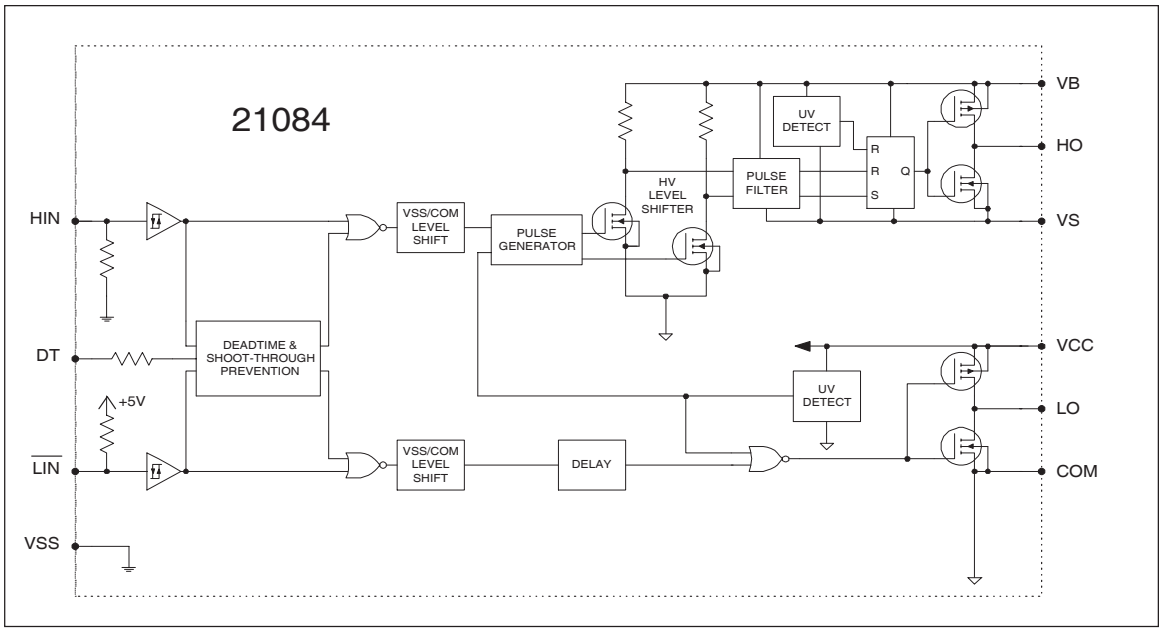
Static Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, V_{SS} = COM, DT= V_{SS} and T_A = 25°C unless otherwise specified. The V_{IL}, V_{IH} and I_{IN} parameters are referenced to V_{SS}/COM and are applicable to the respective input leads: $\overline{HIN}$ and LIN. The V_O, I_O and Ron parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V_{IH}	Logic “1” input voltage for HIN & logic “0” for $\overline{LIN}$	2.9	—	—	V	V_{CC} = 10V to 20V
V_{IL}	Logic “0” input voltage for HIN & logic “1” for $\overline{LIN}$	—	—	0.8		V_{CC} = 10V to 20V
V_{OH}	High level output voltage, V_{BIAS} - V_O	—	0.8	1.4		I_O = 20 mA
V_{OL}	Low level output voltage, V_O	—	0.3	0.6		I_O = 20 mA
I_{LK}	Offset supply leakage current	—	—	50	µA	V_B = V_S = 600V
I_{QBS}	Quiescent V_{BS} supply current	20	75	130		V_{IN} = 0V or 5V
I_{QCC}	Quiescent V_{CC} supply current	0.4	1.0	1.6	mA	V_{IN} = 0V or 5V RDT=0
I_{IN+}	Logic “1” input bias current	—	5	20	µA	HIN = 5V, $\overline{LIN}$ = 0V
I_{IN-}	Logic “0” input bias current	—	—	2		HIN = 0V, $\overline{LIN}$ = 5V
V_{CCUV+} V_{BSUV+}	V_{CC} and V_{BS} supply undervoltage positive going threshold	8.0	8.9	9.8	V	
V_{CCUV-} V_{BSUV-}	V_{CC} and V_{BS} supply undervoltage negative going threshold	7.4	8.2	9.0		
V_{CCUVH} V_{BSUVH}	Hysteresis	0.3	0.7	—		
I_{O+}	Output high short circuit pulsed current	120	200	—	mA	V_O = 0V, PW ≤ 10 µs
I_{O-}	Output low short circuit pulsed current	250	350	—		V_O = 15V, PW ≤ 10 µs

Functional Block Diagram

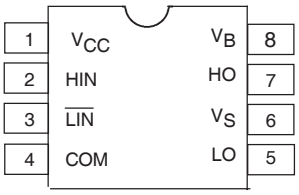




Lead Definitions

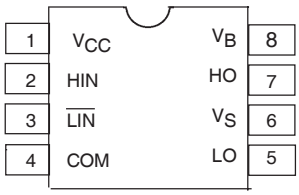
Symbol	Description
HIN	Logic input for high side gate driver output (HO), in phase (referenced to COM for IR2108 and VSS for IR21084)
$\overline{\text{LIN}}$	Logic input for low side gate driver output (LO), out of phase (referenced to COM for IR2108 and VSS for IR21084)
DT	Programmable dead-time lead, referenced to VSS. (IR21084 only)
VSS	Logic Ground (21084 only)
V_B	High side floating supply
HO	High side gate driver output
V_S	High side floating supply return
V_{CC}	Low side and logic fixed supply
LO	Low side gate driver output
COM	Low side return

Lead Assignments



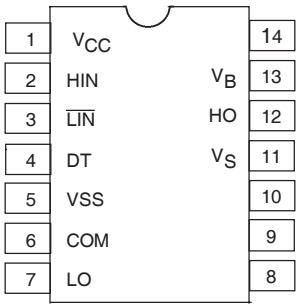
8 Lead PDIP

IR2108



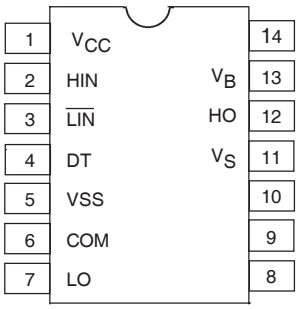
8 Lead SOIC

IR2108S



14 Lead PDIP

IR21084



14 Lead SOIC

IR21084S

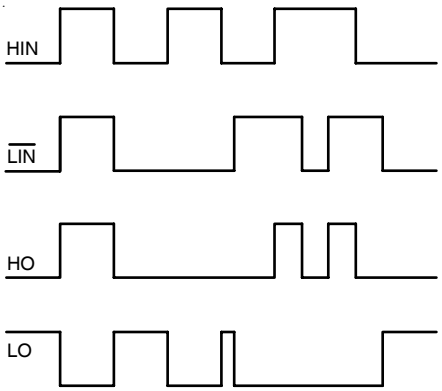
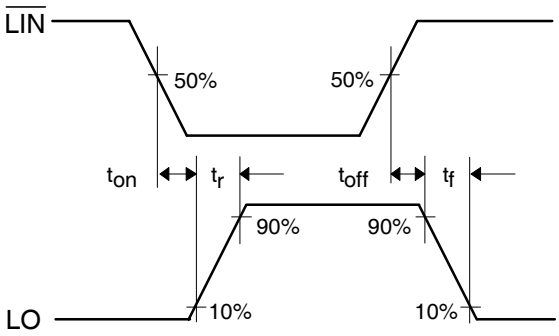


Figure 1. Input/Output Timing Diagram



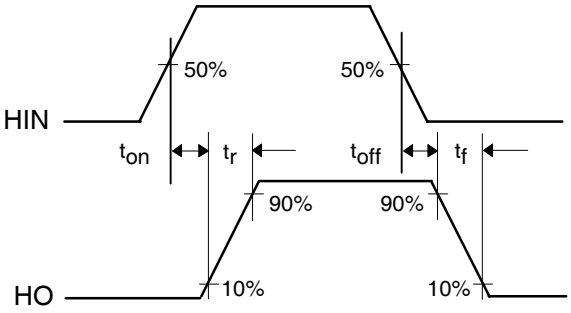


Figure 2. Switching Time Waveform Definitions

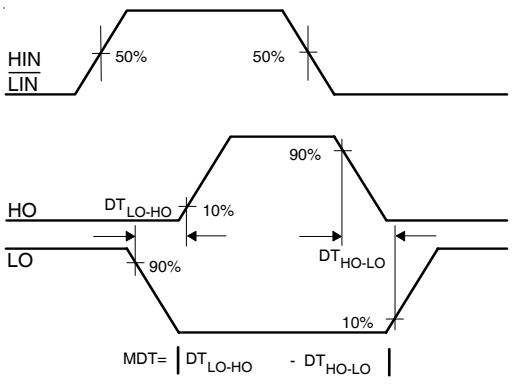


Figure 3. Deadtime Waveform Definitions

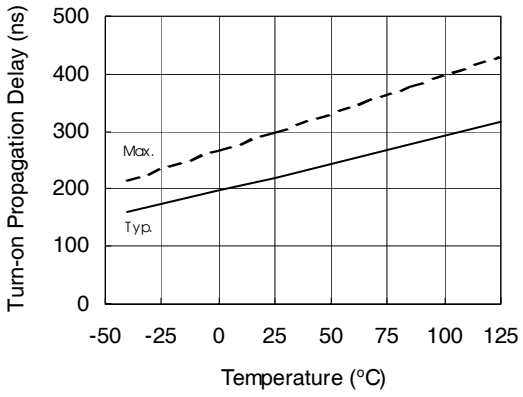


Figure 4A. Turn-on Propagation Delay vs. Temperature

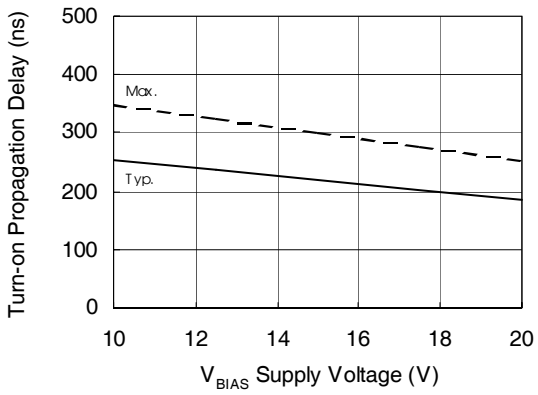


Figure 4B. Turn-on Propagation Delay vs. Supply Voltage

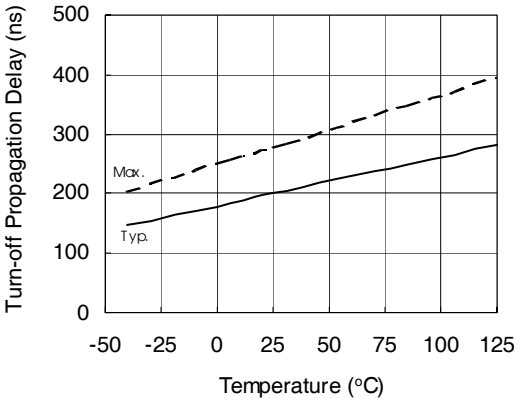


Figure 5A. Turn-off Propagation Delay vs.Temperature

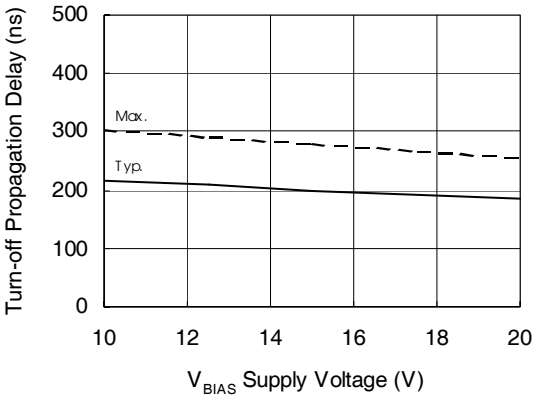


Figure 5B. Turn-off Propagation Delay vs. Supply Voltage

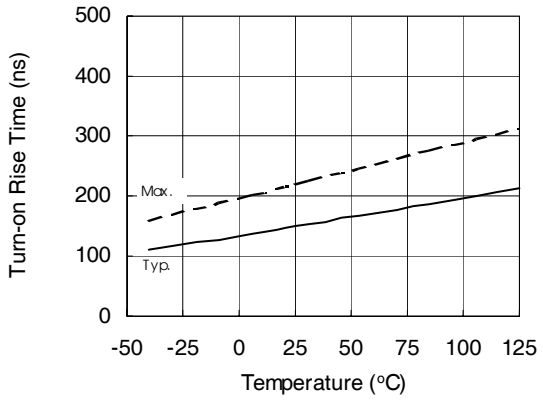


Figure 6A.Turn-on Rise Time vs. Temperature

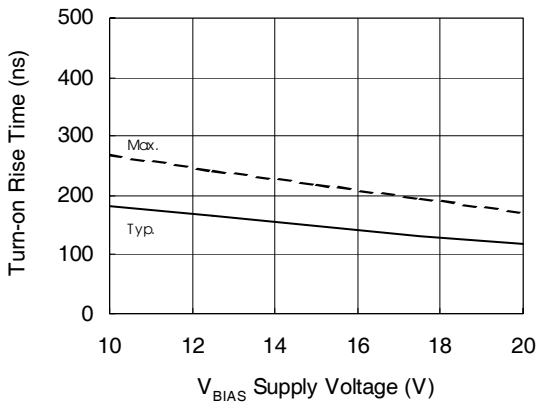


Figure 6B. Turn-on Rise Time vs. Supply Voltage

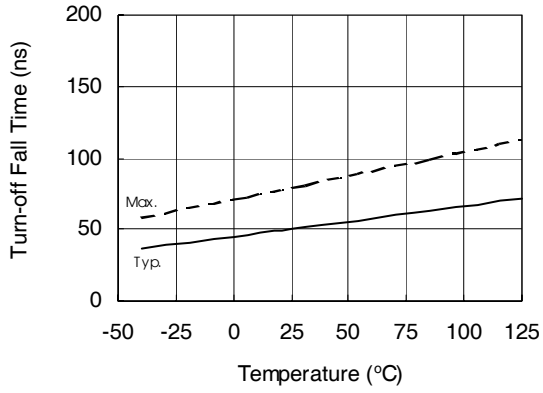


Figure 7A. Turn-off Fall Time vs. Temperature

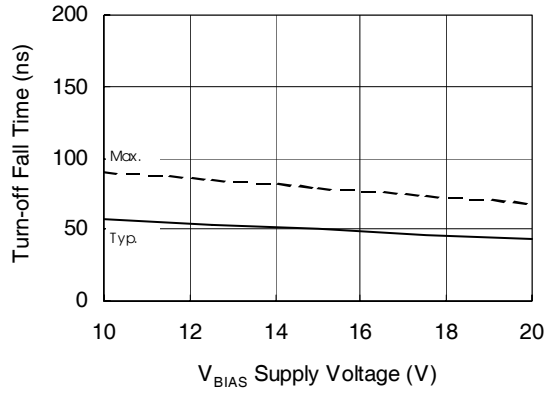


Figure 7B. Turn-off Fall Time vs. Supply Voltage

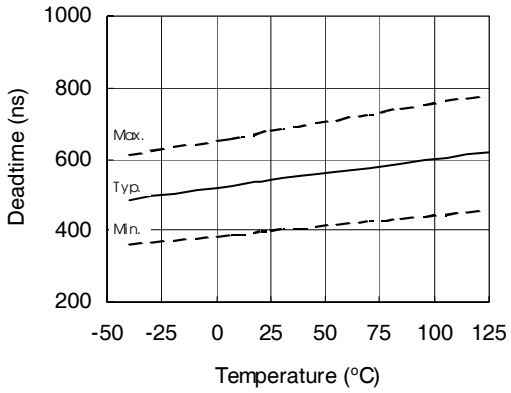


Figure 8A. Deadtime vs. Temperature

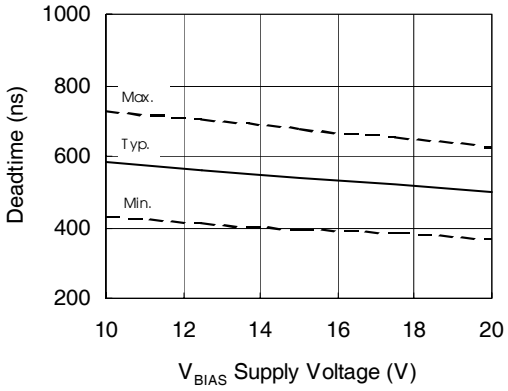


Figure 8B. Deadtime vs. Supply Voltage

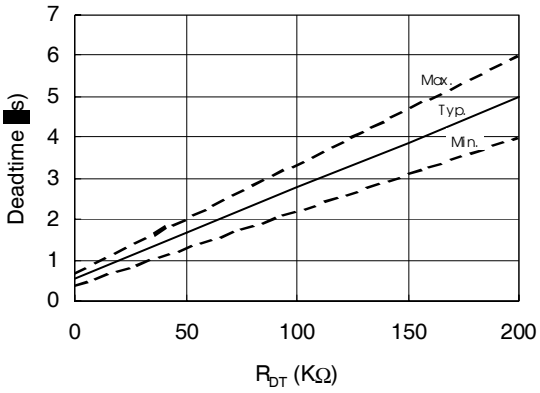


Figure 8C. Deadtime vs. R_{DT} (IR21084 Only)

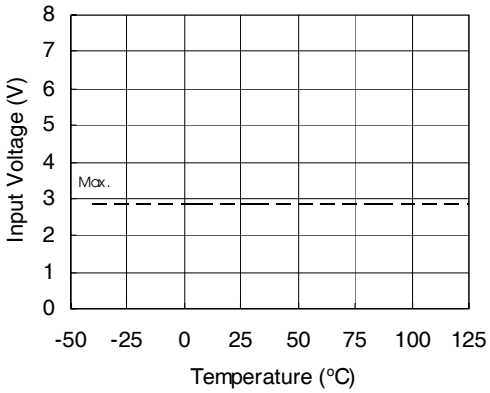


Figure 9A. Logic "1" Input Voltage vs. Temperature

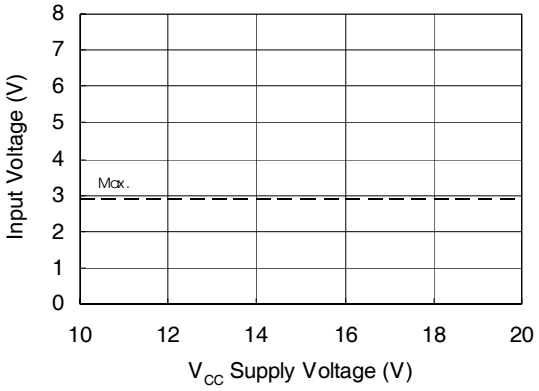


Figure 9B. Logic "1" Input Voltage vs. Supply Voltage

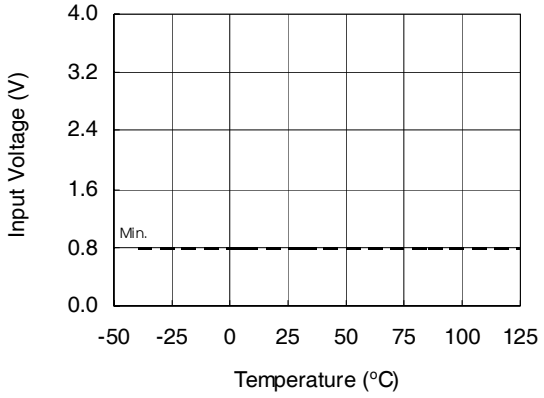


Figure 10A. Logic "0" Input Voltage vs. Temperature

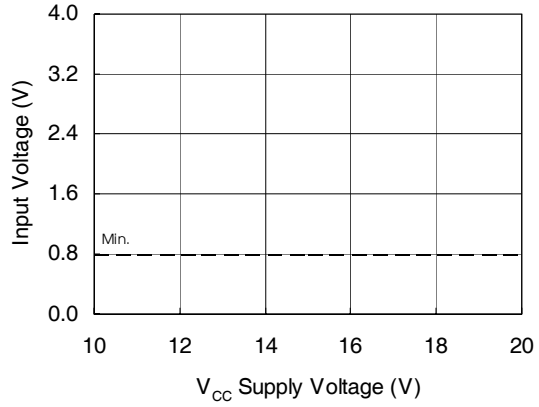


Figure 10B. Logic "0" Input Voltage vs. Supply Voltage

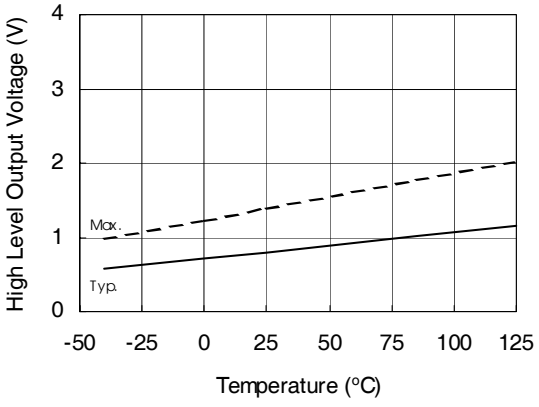


Figure 11A. High Level Output vs. Temperature

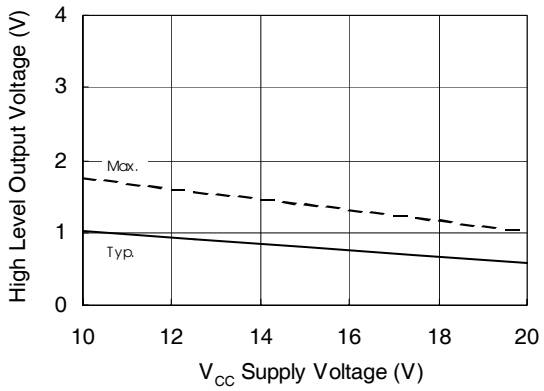


Figure 11B. High Level Output vs. Supply Voltage

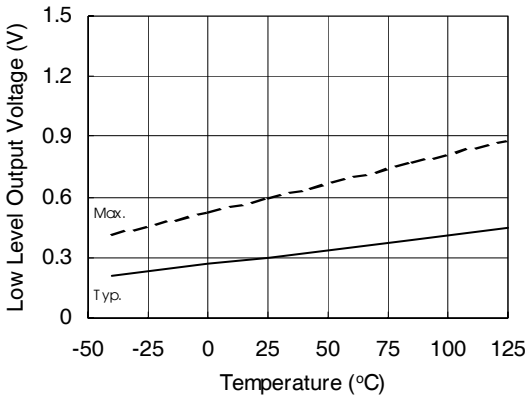


Figure 12A. Low Level Output vs. Temperature

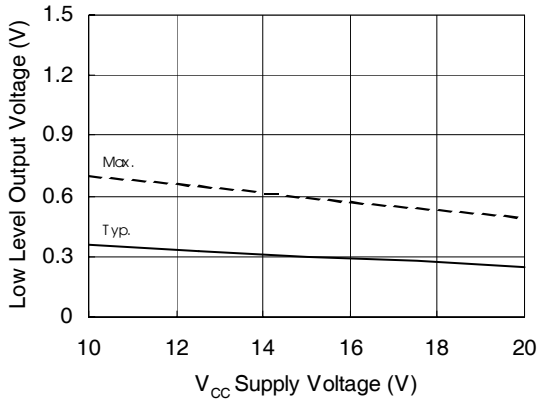


Figure 12B. Low Level Output vs. Supply Voltage

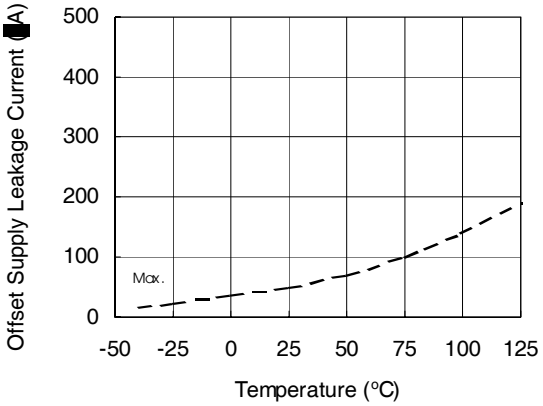


Figure 13A. Offset Supply Leakage Current vs. Temperature

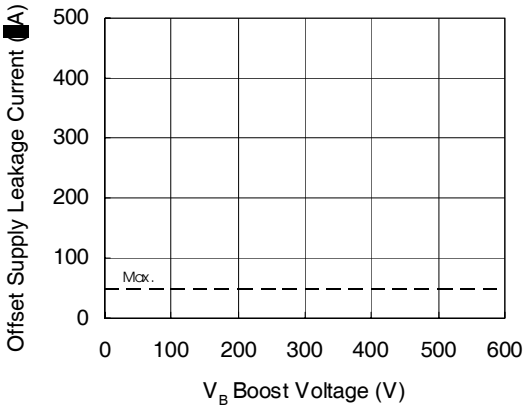


Figure 13B. Offset Supply Leakage Current vs. Temperature

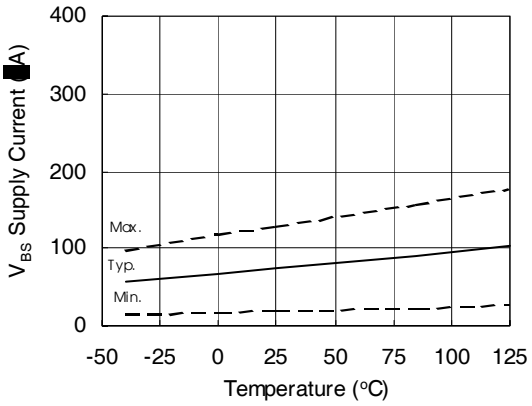


Figure 14A. V_{BS} Supply Current vs. Temperature

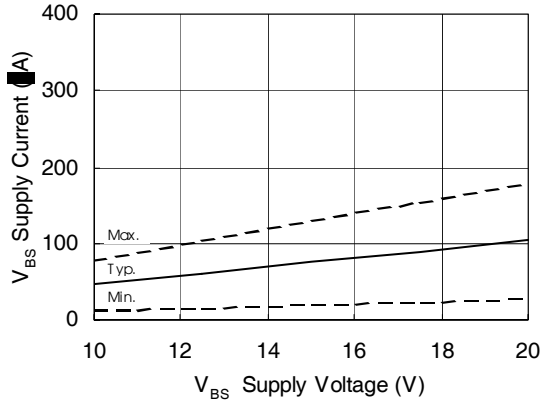


Figure 14B. V_{BS} Supply Current vs. Supply Voltage

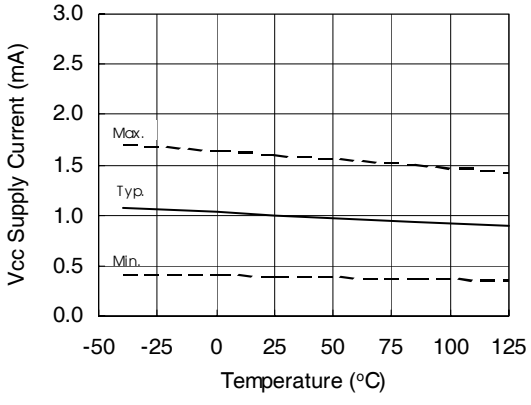


Figure 15A. V_{CC} Supply Current vs. Temperature

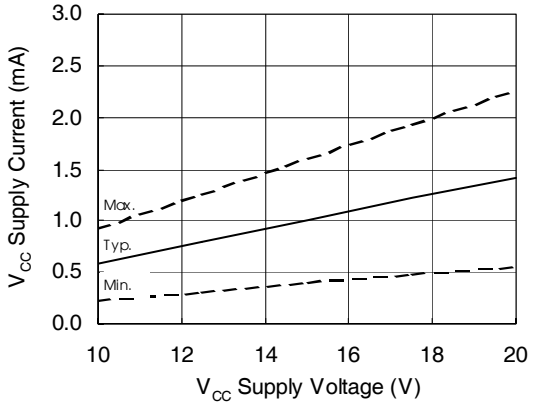


Figure 15B. V_{CC} Supply Current vs. Supply Voltage

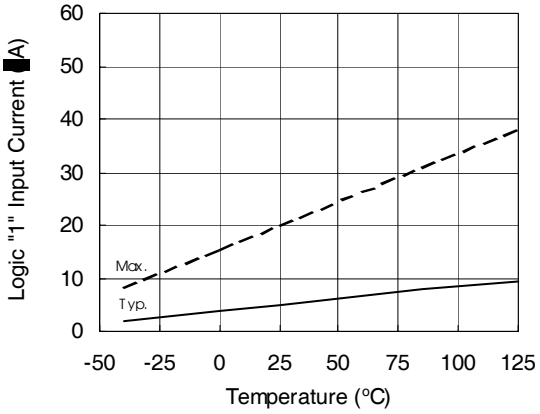


Figure 16A. Logic "1" Input Current vs. Temperature

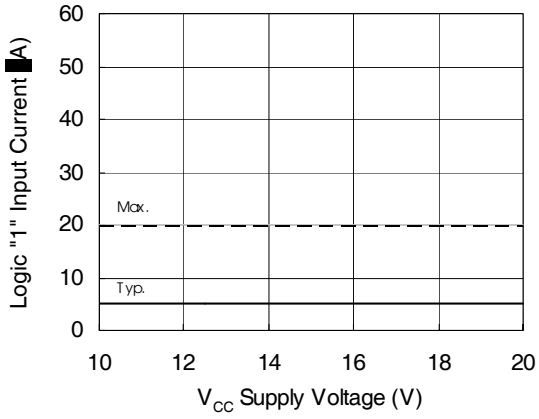


Figure 16B. Logic "1" Input Current vs. Supply Voltage

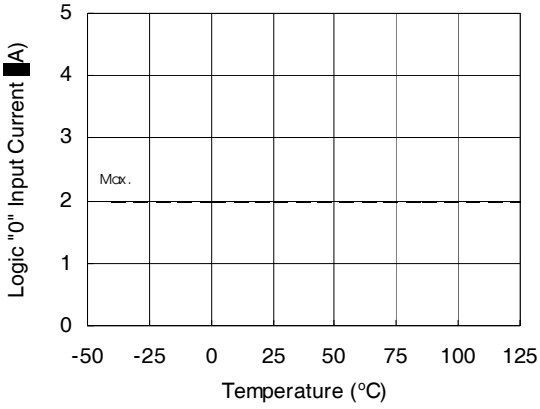


Figure 17A. Logic "0" Input Current vs. Temperature

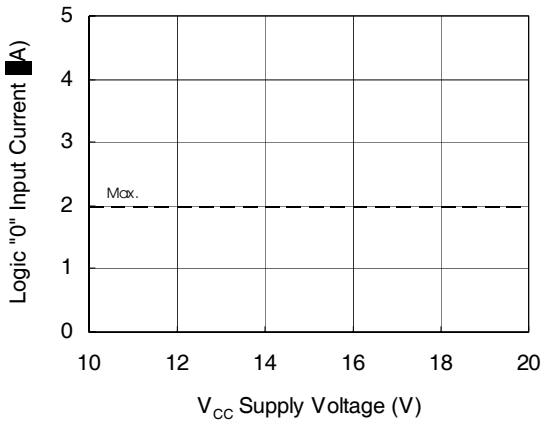


Figure 17B. Logic "0" Input Current vs. Supply Voltage

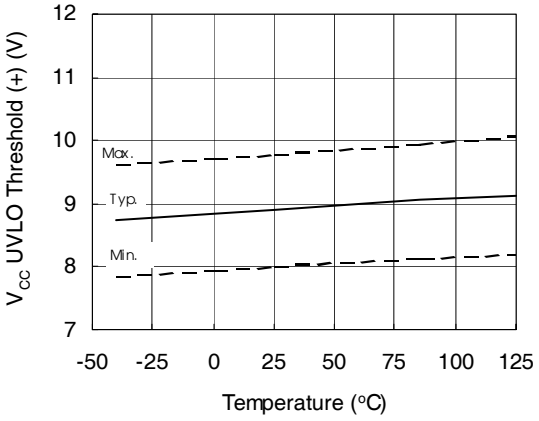


Figure 18. V_{CC} Undervoltage Threshold (+) vs. Temperature

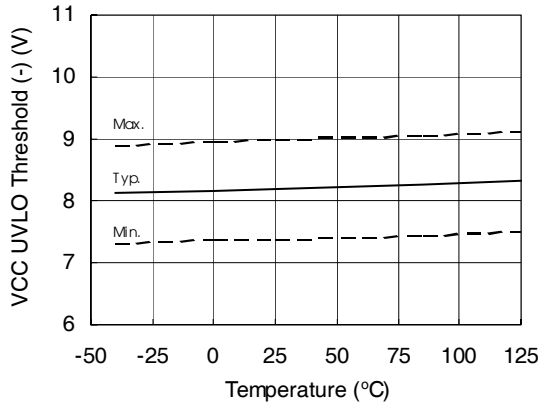


Figure 19. V_{CC} Undervoltage Threshold (-) vs. Temperature

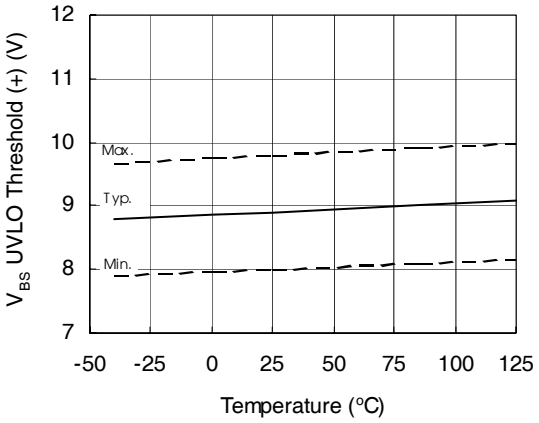


Figure 20. V_{BS} Undervoltage Threshold (+) vs. Temperature

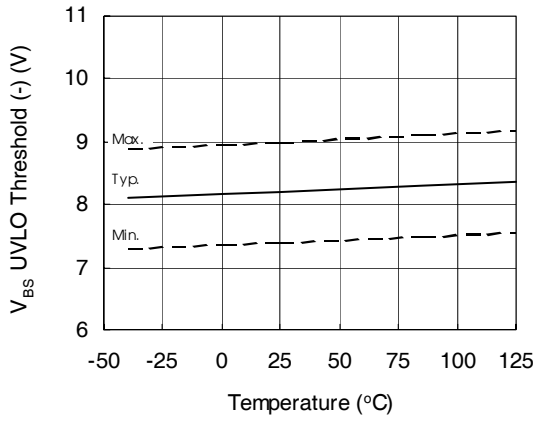


Figure 21. V_{BS} Undervoltage Threshold (-) vs. Temperature

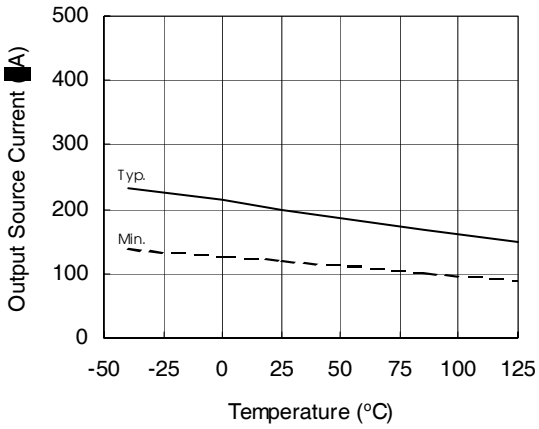


Figure 22A. Output Source Current vs. Temperature

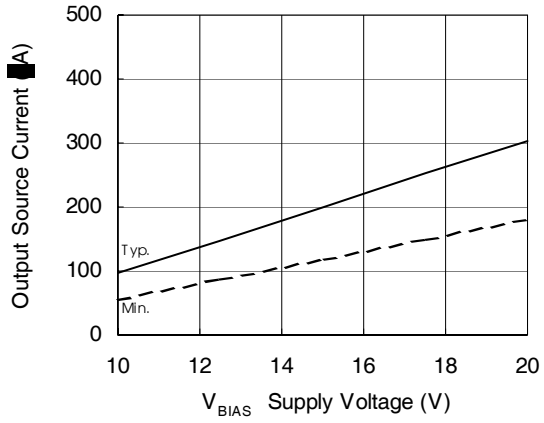


Figure 22B. Output Source Current vs. Supply Voltage

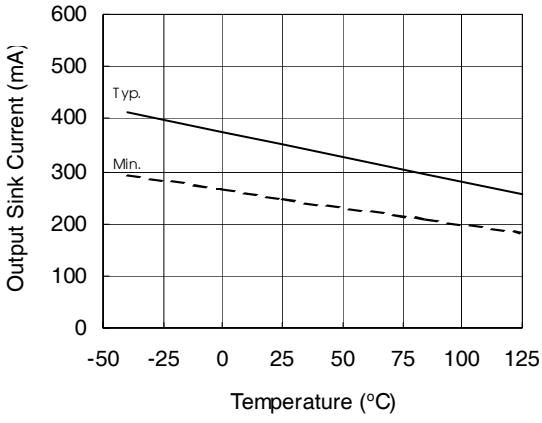


Figure 23A. Output Sink Current vs. Temperature

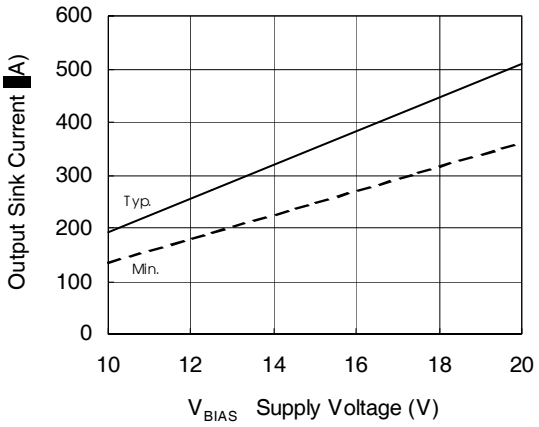


Figure 23B. Output Sink Current vs. Supply Voltage

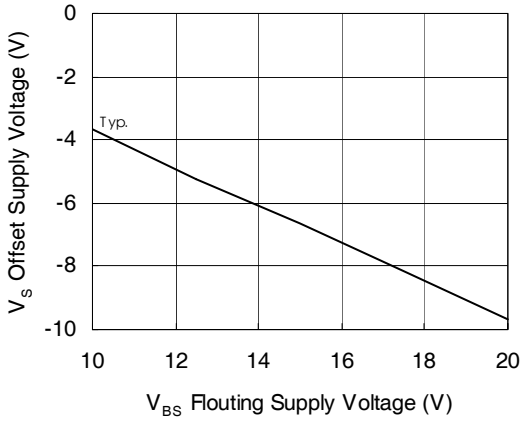


Figure 24. Maximum V_s Negative Offset vs. Supply Voltage

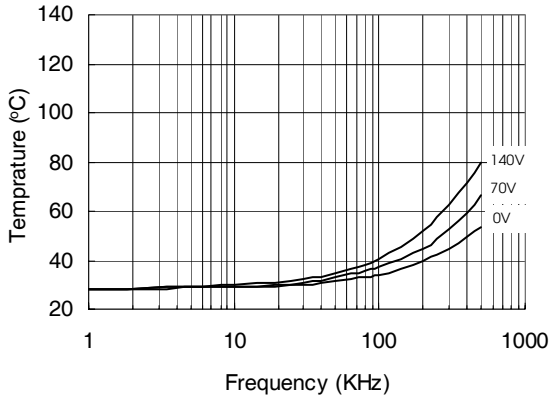


Figure 25. IR2108 vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

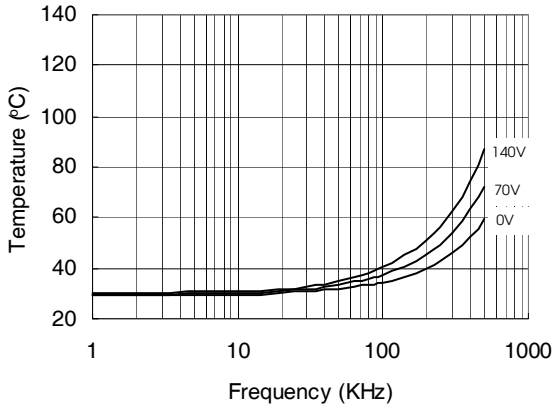


Figure 26. IR2108 vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

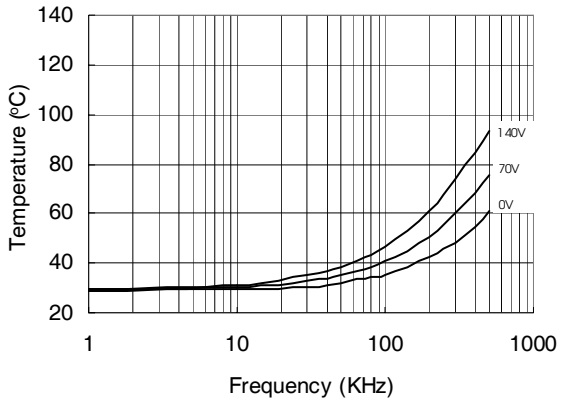


Figure 27. IR2108 vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

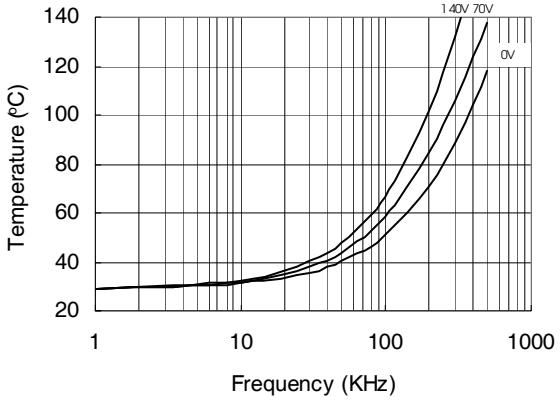


Figure 28. IR2108 vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

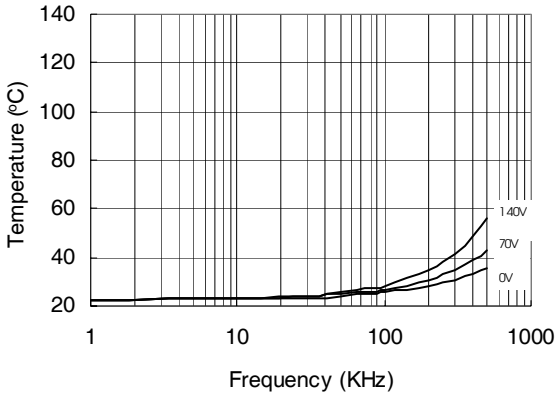


Figure 29. IR21084 vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

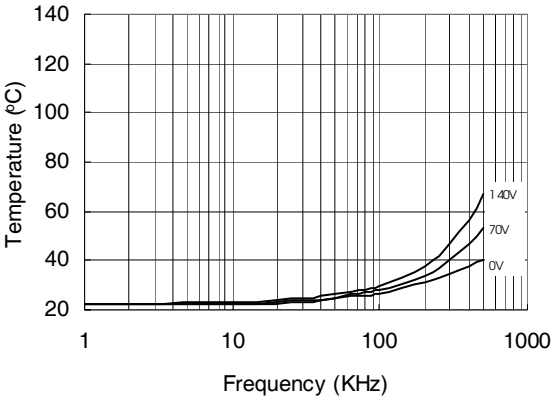


Figure 30. IR21084 vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

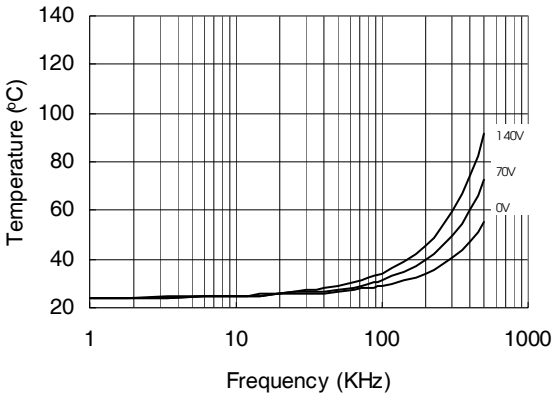


Figure 31. IR21084 vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

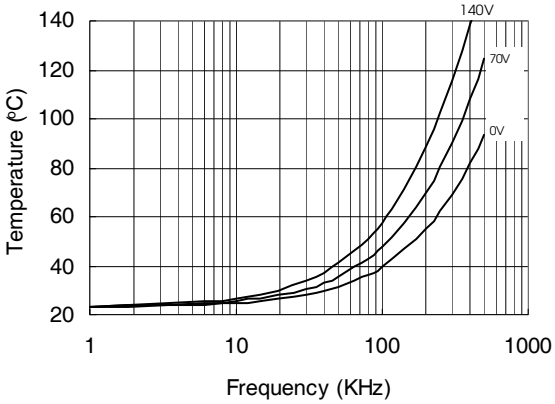


Figure 32. IR21084 vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

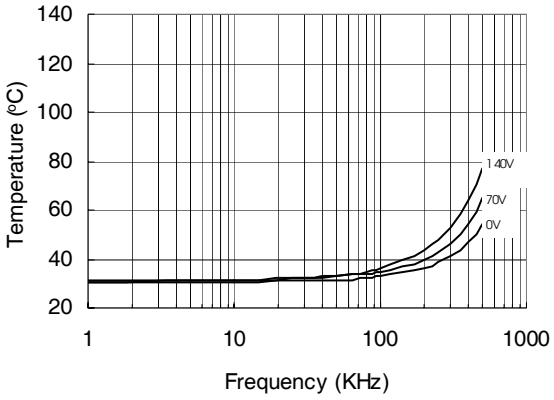


Figure 33. IR2108S vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

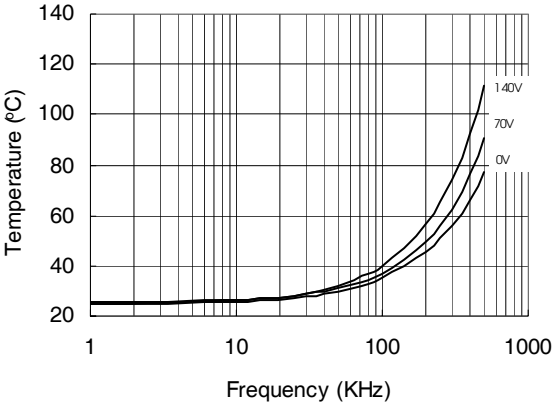


Figure 34. IR2108S vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

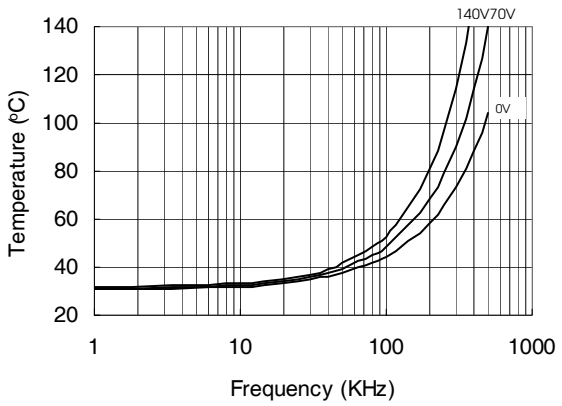


Figure 35. IR2108S vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

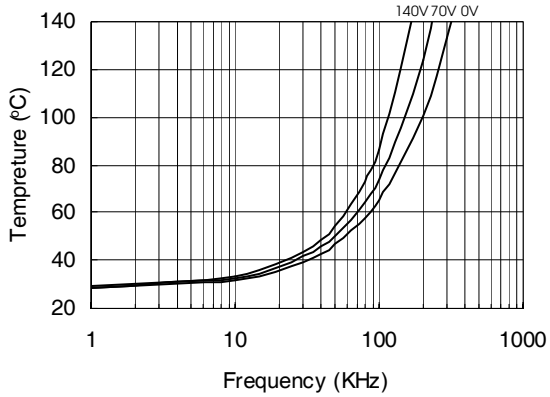


Figure 36. IR2108S vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

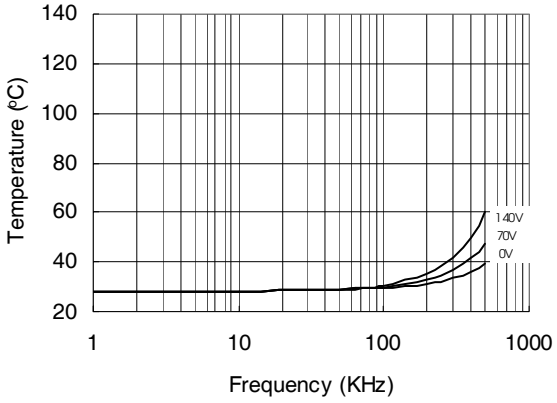


Figure 37. IR21084S vs. Frequency (IRFBC20), R_{gate}=33Ω, V_{CC}=15V

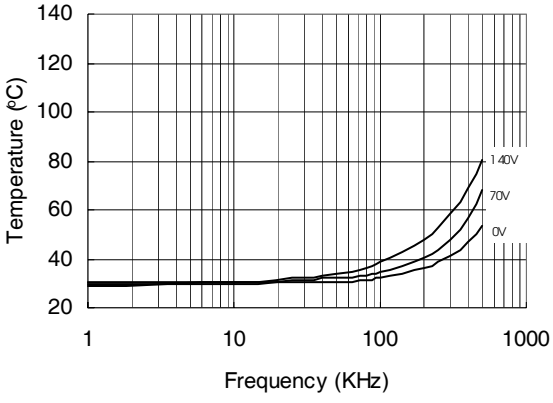


Figure 38. IR21084S vs. Frequency (IRFBC30), R_{gate}=22Ω, V_{CC}=15V

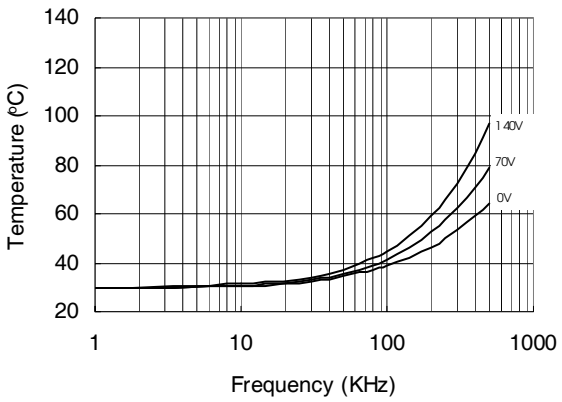


Figure 39. IR21084S vs. Frequency (IRFBC40), R_{gate}=15Ω, V_{CC}=15V

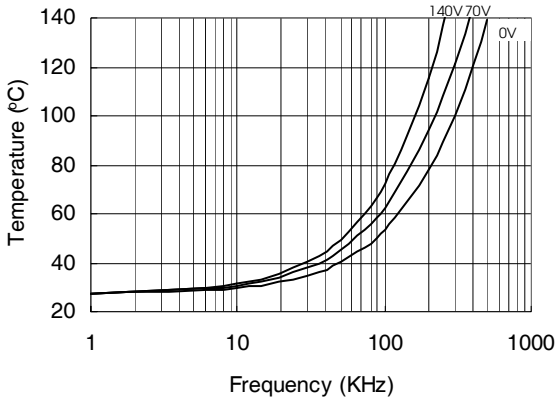
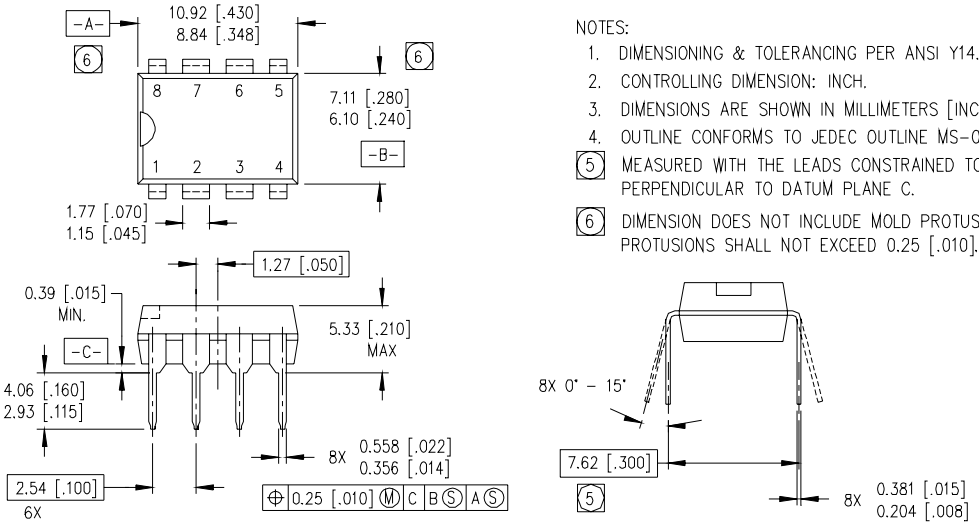


Figure 40. IR21084S vs. Frequency (IRFPE50), R_{gate}=10Ω, V_{CC}=15V

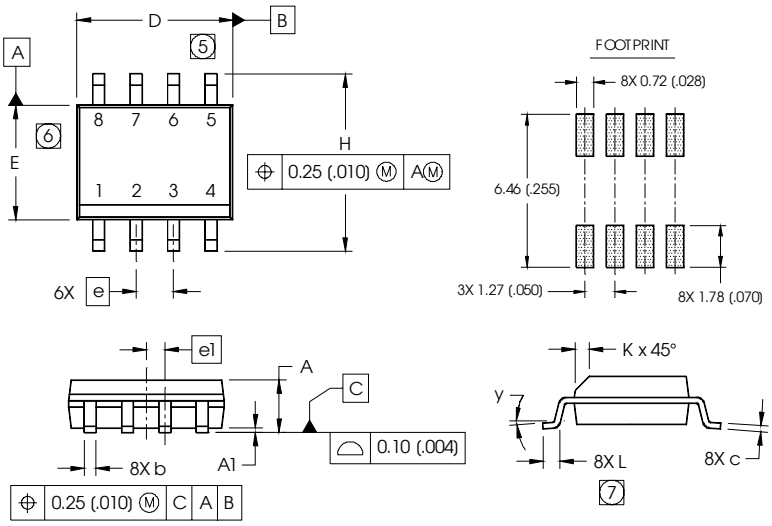
Case outlines



NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-001AB.
5. MEASURED WITH THE LEADS CONSTRAINED TO BE PERPENDICULAR TO DATUM PLANE C.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.25 [.010].

8-Lead PDIP

01-6014
01-3003 01 (MS-001AB)

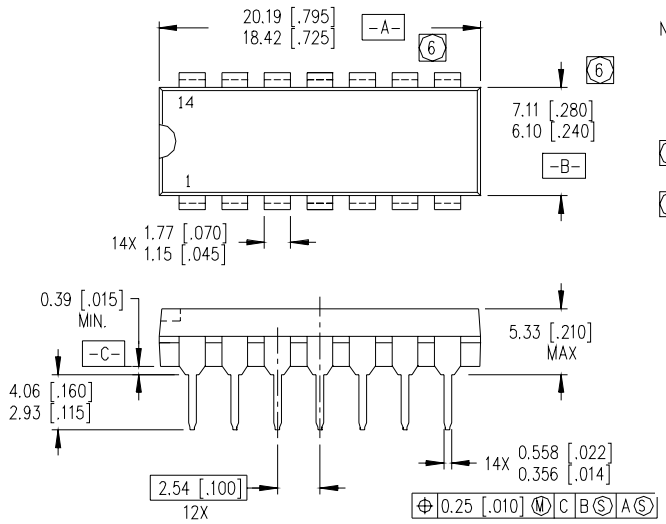


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.0532	.0688	1.35	1.75
A1	.0040	.0098	0.10	0.25
b	.013	.020	0.33	0.51
c	.0075	.0098	0.19	0.25
D	.189	.1968	4.80	5.00
E	.1497	.1574	3.80	4.00
e	.050 BASIC		1.27 BASIC	
e1	.025 BASIC		0.635 BASIC	
H	.2284	.2440	5.80	6.20
K	.0099	.0196	0.25	0.50
L	.016	.050	0.40	1.27
y	0°	8°	0°	8°

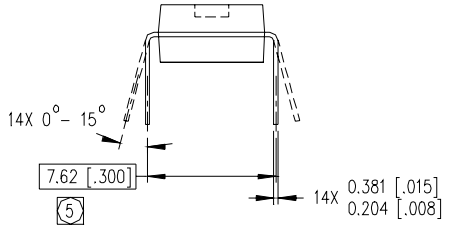
NOTES:
1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
5. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.15 (.006).
6. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS NOT TO EXCEED 0.25 (.010).
7. DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

8-Lead SOIC

01-6027
01-0021 11 (MS-012AA)

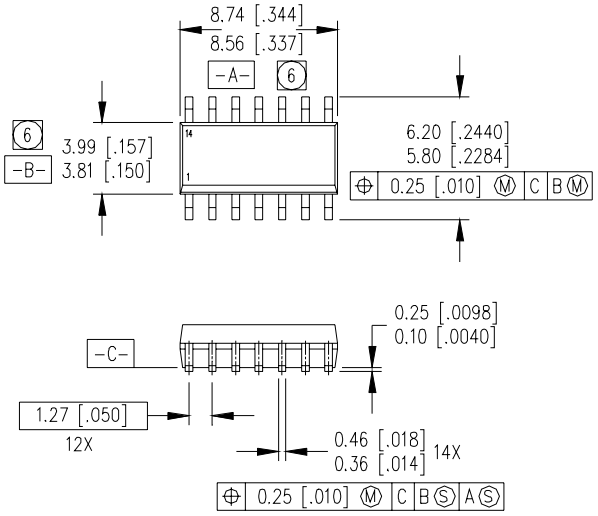


NOTES:
1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-001AC.
5. MEASURED WITH THE LEADS CONSTRAINED TO BE PERPENDICULAR TO DATUM PLANE C.
6. DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.25 [.010].

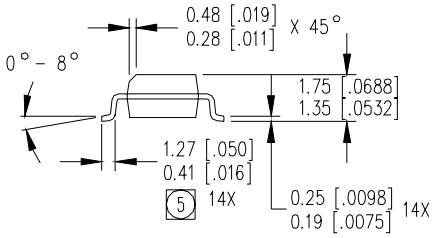


14-Lead PDIP

01-6010
01-3002 03 (MS-001AC)



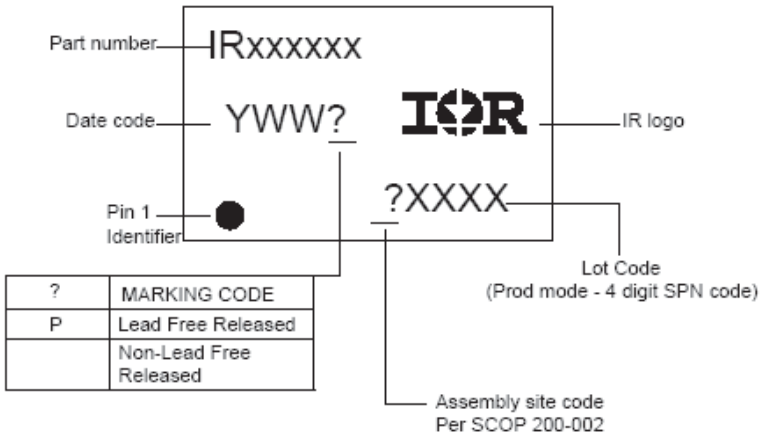
NOTES:
1 DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982.
2 CONTROLLING DIMENSION: MILLIMETER
3 DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4 OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AB.
5 DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.
6 DIMENSION DOES NOT INCLUDE MOLD PROTUSIONS. MOLD PROTUSIONS SHALL NOT EXCEED 0.15 [.006].



14-Lead SOIC (narrow body)

01-6019
01-3063 00 (MS-012AB)

LEADFREE PART MARKING INFORMATION



?	MARKING CODE
P	Lead Free Released
	Non-Lead Free Released

ORDER INFORMATION

Basic Part (Non-Lead Free)				Lead-Free Part			
8-Lead PDIP	IR2108	order	IR2108	8-Lead PDIP	IR2108	order	IR2108PbF
8-Lead SOIC	IR2108S	order	IR2108S	8-Lead SOIC	IR2108S	order	IR2108SPbF
14-Lead PDIP	IR21084	order	IR21084	14-Lead PDIP	IR21084	order	IR21084PbF
14-Lead SOIC	IR21084S	order	IR21084S	14-Lead SOIC	IR21084S	order	IR21084SPbF

International
IOR Rectifier

This product has been designed and qualified for the Industrial market.
Qualification Standards can be found on IR's Website.
Data and specifications subject to change without notice.

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